# **BS108**

Characteristic	Symbol	Min	Тур	Max	Unit
OFF CHARACTERISTICS	L				
Drain-Source Breakdown Voltage $(V_{GS} = 0, I_D = 10 \ \mu A)$	V <sub>(BR)DS</sub>	200	-		Vdc
Zero Gate Voltage Drain Current $(V_{DSS} = 130 \text{ Vdc}, V_{GS} = 0)$	I <sub>DSS</sub>	-	_	30	nAdc
Gate-Body Leakage Current $(V_{GS} = 15 \text{ Vdc}, V_{DS} = 0)$	IGSSF	_	-	10	nAdc
ON CHARACTERISTICS (Note 3)			•		
Gate Threshold Voltage $(I_D = 1.0 \text{ mA}, V_{DS} = V_{GS})$	V <sub>GS(th)</sub>	0.5	-	1.5	Vdc
$      Static Drain-to-Source On-Resistance \\ (V_{GS} = 2.0 \ Vdc, \ I_D = 50 \ mA) \\ (V_{GS} = 2.8 \ Vdc, \ I_D = 100 \ mA) $	r <sub>DS(on)</sub>			10 8.0	Ω
Drain Cutoff Current $(V_{GS} = 0.2 \text{ V}, V_{DS} = 70 \text{ V})$	IDSX	-	_	25	μΑ
Forward Transconductance $(I_D = 120 \text{ mA}, V_{DS} = 20 \text{ V})$	9fs	_	0.33	-	Mhos
DYNAMIC CHARACTERISTICS			•		
Input Capacitance $(V_{DS} = 25 \text{ V}, V_{GS} = 0, \text{ f} = 1.0 \text{ MHz})$	C <sub>iss</sub>	-	-	150	pF
Output Capacitance $(V_{DS} = 25 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1.0 \text{ MHz})$	C <sub>oss</sub>	-	-	30	pF
Reverse Transfer Capacitance $(V_{DS} = 25 \text{ V}, \text{ V}_{GS} = 0, \text{ f} = 1.0 \text{ MHz})$	C <sub>rss</sub>	-	-	10	pF
SWITCHING CHARACTERISTICS	L	•	•		•
Turn-On Time (See Figure 1)	t <sub>d(on)</sub>	-	-	15	ns
Turn-Off Time (See Figure 1)	t <sub>d (off)</sub>	-	-	15	ns
			×		

3. Pulse Test: Pulse Width  $\leq$  300 µs, Duty Cycle = 2.0%.

## **RESISTIVE SWITCHING**

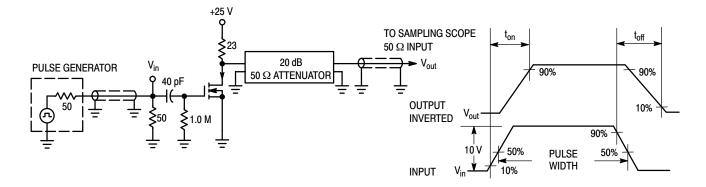


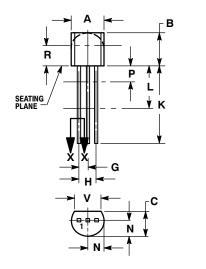
Figure 1. Switching Test Circuit

Figure 2. Switching Waveforms

### **BS108**

### PACKAGE DIMENSIONS

TO-92 (TO-226) CASE 29-11 ISSUE AM



STRAIGHT LEAD BULK PACK



SECTION X-X

NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
   CONTROLLING DIMENSION: INCH.
- CONTROLLING DIMENSION: INCH.
  CONTOUR OF PACKAGE BEYOND DIMENSION R IS UNCONTROLLED.
- LEAD DIMENSION IS UNCONTROLLED IN P AND BEYOND DIMENSION K MINIMUM.

	INCHES		MILLIMETERS		
DIM	MIN	MAX	MIN	MAX	
Α	0.175	0.205	4.45	5.20	
В	0.170	0.210	4.32	5.33	
С	0.125	0.165	3.18	4.19	
D	0.016	0.021	0.407	0.533	
G	0.045	0.055	1.15	1.39	
Η	0.095	0.105	2.42	2.66	
-	0.015	0.020	0.39	0.50	
Κ	0.500		12.70		
Г	0.250		6.35		
Ν	0.080	0.105	2.04	2.66	
Ρ		0.100		2.54	
R	0.115		2.93		
۷	0.135		3.43		

STYLE 30: PIN 1. DRAIN 2. GATE

3. SOURCE

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